

3.3V, 1A-3A Programmable Current Limit Switch with Auto Enable

DESCRIPTION

The MP5003 is a protection device designed to protect circuitry on the output (V_{OUT}) from transients on the input (V_{IN}) . It also protects V_{IN} from undesired shorts and transients coming from the load.

At start up, inrush current is limited by limiting the slew rate at V_{OUT} . The slew rate is controlled by a small capacitor at the dv/dt pin. The dv/dt pin has an internal circuit that allows the customer to float this pin (no connect) and still receive a 1.1ms ramp time at V_{OUT} .

The max load at the output (V_{OUT}) is current limited. This is accomplished by utilizing a sense FET topology. The magnitude of the current limit is controlled by an external resistor connected between the I_{LIMIT} pins.

An internal charge pump drives the gate of the power device, allowing a very low on-resistance DMOS power FET of just $44m\Omega$.

 V_{OUT} is protected from V_{IN} being too low or too high. Under Voltage Lockout (UVLO) assures that the input is above the minimum operating threshold, before the power device is turned on. If V_{IN} goes above the high output threshold, the output voltage will be limited.

FEATURES

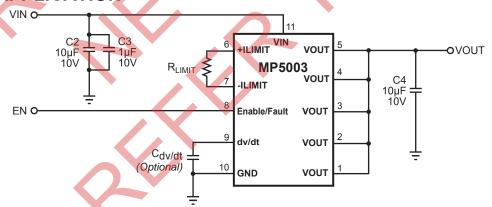
- Integrated 44mΩ Power FET
- Enable/Fault Pin
- Adjustable Slew Rate for Output Voltage
- Adjustable Current Limit: 1A-3A
- Automatically Startup after Thermal Protection
- Over Voltage Limit

APPLICATIONS

- Hot Swap
- PC Cards
- Cell Phones
- Laptops

"MPS" and "The Future of Analog IC Technology" are Registered Trademarks of Monolithic Power Systems, Inc.

TYPICAL APPLICATION



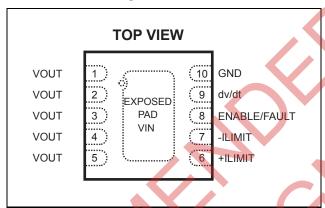


ORDERING INFORMATION

Part Number*	Package	Top Marking	Free Air Temperature (TA)
MP5003EQ	QFN10 (3x3)	7M	-20°C to +85°C

* For Tape & Reel, add suffix –Z (e.g. MP5003EQ–Z); For RoHS Compliant Packaging, add suffix –LF (e.g. MP5003EQ–LF–Z

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

V _{IN} , V _{OUT} , +I _{LIMIT} , -I _{LIMIT}		22V
dv/dt, ENABLE/FAULT		6V
Continuous Power Dissipation	า (T _A =+2	5°C) ⁽²⁾
Storage Temperature	65°C	to +155°C
Junction Temperature	-20°C t	o +150°C

Recommended Operating Conditions

Input Voltage Operating Range......2.5V to 6V Operating Junct.Temp(T_J)......-20°C to +125°C

Thern	nal Resis	tance (3)	θ_{JA}	θ_{JC}
QFN10			50	12°C/W

Notes:

- 1) Exceeding these ratings may damage the device..
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature $T_J(\text{MAX})$, the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A the maximum allowable power dissipation at any ambient temperature is calculated using: $P_D(\text{MAX}) = (T_J(\text{MAX}) T_A)/$ θ_{JA} . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
 - Reduce 0.2 Watts for every 10°C ambient temperature increasing
- Measured on JESD51-7 4-layer board.



ELECTRICAL CHARACTERISTICS

 V_{IN} = 3.3V, R_{LIMIT} =24 Ω , C_{OUT} = 10 μ F, T_{J} =25 $^{\circ}$ C, unless otherwise noted.

		Condition	Min	Тур	Max	Units
Power FET						
Delay Time	t _{DLY}	Enabling of chip to I_D =100mA with a 12 Ω resistive load		0.2		ms
ON Resistance	R _{DSon}	T _J =+25°C T _J =+80°C, Note 4		44 95	82	mΩ
Off State Output Voltage	V _{OFF}	Enable=0V,R _L =500Ω			120	mV
Thermal Latch	_					
Shutdown Temperature	T _{SD}	Note 4		175		°C
Under/Over Voltage Protection	_				r	
Output Clamping Voltage	V_{CLAMP}	Overvoltage Protection V _{IN} = 6V	3.63	4.03	4.43	V
Under Voltage Lockout	V _{UVLO}	Turn on, Voltage going high	2.15	2.35	2.5	V
Under Voltage Lockout (UVLO) Hysteresis	V _{HYST}		1	100	400	mV
Current Limit						
Short Circuit Current Limit (Hold Current)	I _{LIM}	R_{LIMIT} =24 Ω , Note 4	1.2	1.55	1.9	Α
Trip Current ILIM-OL		R _{LIMIT} =24Ω, Note 4	2.0	2.5	3.0	Α
dv/dt Circuit						
Rise Time	Τŗ	Float dv/dt pin, Note 5	0.64	1,1	2.0	ms
Enable/Fault		7,0				
Low Level Input Voltage	V _{IL}	Output Disabled			0.5	V
High Level Input Voltage	V _{IH}	Output Enabled	2.5			V
High State Maximum Voltage	$V_{I (MAX)}$			3.25		V
Low Level Input Current (Sink)	I _{IL}	V _{ENABLE} =0V		-55	-75	μΑ
Maximum Fanout for Fault Signal		Total number of chips that can be connected for simultaneous shutdown			5	Units
Maximum Voltage on Enable Pin	V_{MAX}	Note 6			V_{IN}	V
Total Device						
D: 0		Device Operational		1.5	2.0	
Bias Current	BIAS	Thermal Shutdown		0.9		mA
Minimum Operating Voltage for UVLO	V _{MIN}	Enable<0.5V			2.0	V

Notes:

- 4) Guaranteed by design.
- 5) Measured from 10% to 90%.
- 6) Maximum Input Voltage to be \leq 6V if $V_{IN} \geq$ 6V. Maximum Input Voltage to be V_{IN} if $V_{IN} \leq$ 6V.



PIN FUNCTIONS

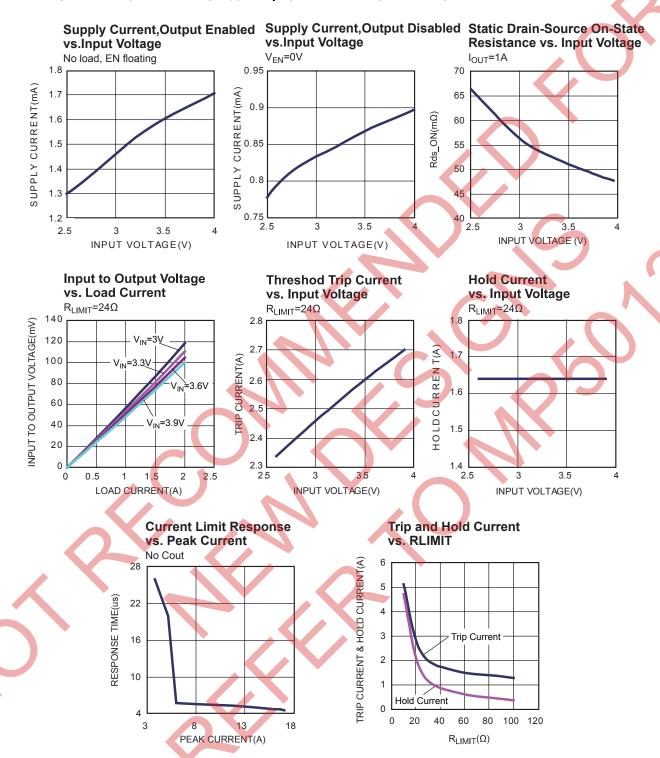
Pin#	Name	Description
1-5	VOUT	This pin is the V _{OUT} of the internal power FET and the output terminal of the IC.
6	+ILIMIT	A resistor between these pins sets the overload and short circuit current limit levels.
7	-ILIMIT	A resistor between these pins sets the overload and short circuit current limit levels.
8	Enable/Fault	The Enable/Fault pin is a bi-directional interface. It can be used to enable the output of the device by floating the pin, or disable the chip by pulling it to ground (using an open drain or open collector device). If a thermal fault occurs, the voltage on this pin will drive to ground, automatically.
9	dv/dt	The internal dv/dt circuit controls the slew rate of the output voltage at turn on. It has an internal capacitor that allows it to ramp up over the period of 1.1ms. An external capacitor can be added to this pin to increase the ramp time. If an additional time delay is not required, this pin should be left open.
10	GND	Negative Input Voltage to the Device. This is used as the internal reference for the IC.
11	VIN	Positive input voltage to the device (Exposed Pad).





TYPICAL PERFORMANCE CHARACTERISTICS

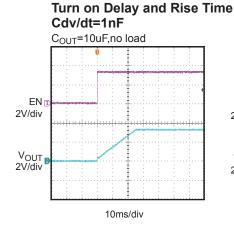
 V_{IN} =3.3V, V_{EN} =3.3V, R_{LIMIT} =24 Ω , C_{OUT} =10 μ F, Cdv/dt=1nF, T_{A} =25°C, unless otherwise noted.

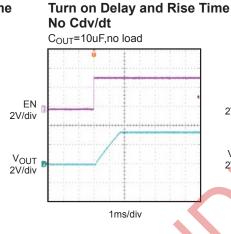




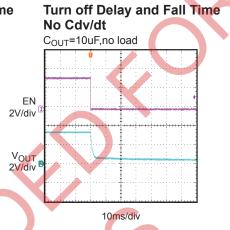
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

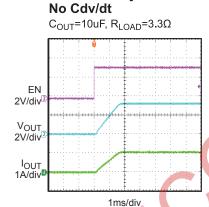
 V_{IN} =3.3V, V_{EN} =3.3V, R_{LIMIT} =24 Ω , C_{OUT} =10 μ F, Cdv/dt=1nF, T_{A} =25°C, unless otherwise noted.





Turn off Delay and Fall Time

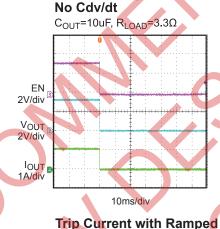


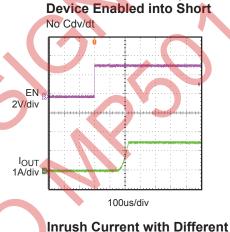


Short Circuit Current.

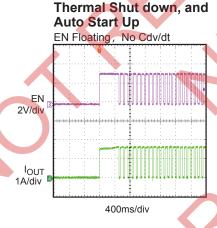
Device Enabled into Short,

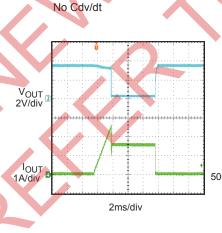
Turn on Delay and Rise Time



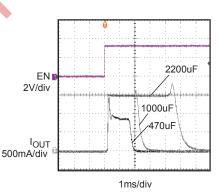


Short Circuit Current,





Load on Enabled Device



Load Capacitance

No Cdv/dt

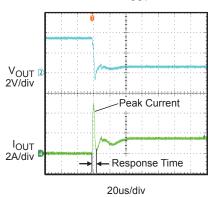


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 V_{IN} =3.3V, V_{EN} =3.3V, R_{LIMIT} =24 Ω , C_{OUT} =10 μ F, Cdv/dt=1nF, T_A =25°C, unless otherwise noted.

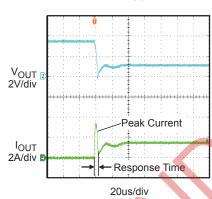
0.33Ω Load Connected to Enabled Device

No Cdv/dt, No C_{OUT}

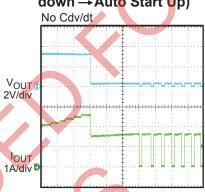


0.66Ω Load Connected to Enabled Device

No Cdv/dt, No C_{OUT}



Current Limit (trip →hold →thermal shut down →Auto Start Up)



200ms/div

© 2012 MPS. All Rights Reserved.

BLOCK DIAGRAM

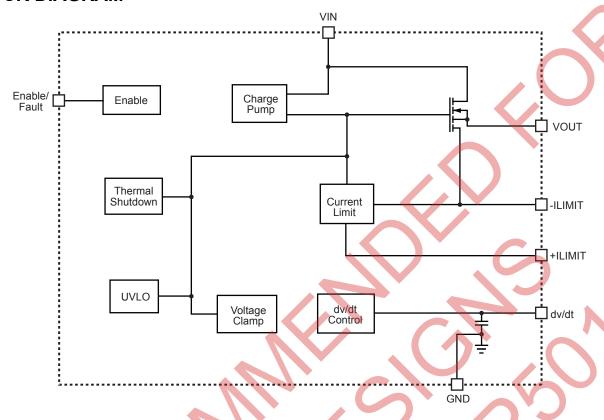


Figure 1—Function Block Diagram



CURRENT LIMIT

The desired current limit is a function of the external current limit resistor.

Table 1—Current Limit vs. Current Limit Resistor (V_{IN}=3.3V)

Current Limit Resistor (Ω)	13	24	50	100
Trip Current (A)	4	2.5	1.7	1.37
Hold Current (A)	3.2	1.55	0.77	0.37

When the part is active, if load reaches trip current (minimum threshold current triggering overcurrent protection) or a short is present, the part switches into to a constant-current (hold current) mode. Part will enter thermal cycling only if the overcurrent condition stays long enough to trigger thermal protection.

However, when the part is powered up by V_{CC} or EN, the load current should be smaller than hold current. Otherwise, the part can't be fully turned on.

In a typical application using a current limit resistor of 24Ω , the trip current will be 2.5A and the hold current will be 1.55A. If the device is in its normal operating state and passing 1.5A it will need to dissipate only 99mW with the very low on resistance of $44m\Omega$. For the package dissipation of 50°C/Watt , the temperature rise will only be + 5°C . Combined with a 25°C ambient, this is only 30°C total package temperature.

During a short circuit condition, the device now has 3.3V across it and the hold current clamps at 1.55A and therefore must dissipate 5W. At 50°C/watt, if uncontrolled, the temperature would rise above the thermal protection threshold (+175°C) and the device will shutdown to cause the temperature to drop.

Proper heat sink must be used if the device is intended to supply the hold current and not shutdown. Without a heat sink, hold current should be maintained below 909mA at + 25°C and below 545mA at +85°C to prevent the device from activating the thermal shutdown feature.

RISE TIME

The rise time is a function of the capacitor (Cdv/dt) on the dv/dt pin.

Table 2-Rise Time vs. Cdv/dt.

Cdv/dt	none	50pF	500pF	1nF
Rise Time (TYPICAL) (ms)	1.1	2.2	12.3	23.5

^{*} Notes: Rise Time = K_{RT} *(50pF+ $C_{dv/dt}$), K_{RT} =22E6

The "rise time" is measured by from 10% to 90% of output voltage.

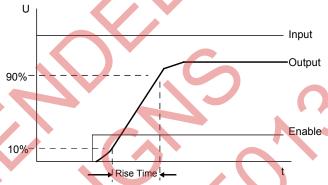


Figure 2—Rise Time

FAULT AND ENABLE PIN

The Enable/Fault Pin is a Bi-Directional I/O with a weak pull up current (25uA typical). It functions to enable/disable the part.

Enable pin as an input:

- 1. Low disables the part.
- 2. High enables the part.

Enable pin as an output:

- 1. The pull up current may (if not over ridden) allow a "wired nor" pull up to enable the part.
- 2. An under voltage will cause a low on the enable pin.
- 3. A thermal fault will cause a low level on the enable pin.



There are 4 types of faults, and each fault has a direct and indirect effect on the Enable/Fault pin and the internal fault flag. In a typical application where there are multiple MP5003 chips in a system, the enable/fault lines are typically connected together.

UNDER VOLTAGE LOCK OUT OPERATION

If the supply (input) is below the UVLO threshold, the output is disabled, and the fault line is driven low.

When the supply goes above the UVLO threshold, the output is enabled and the Enable/fault pin is released. When the Enable/fault pin is released it will be pulled high by a 25uA current source. No external pull up resistor is required. In addition, the pull up voltage is limited to 5 volts.

Table 3—Fault Function Influence in Application

Fault description	Internal action	Effect on Fault Pin	Effect on Flag	Effect on secondary Part
Short/over current	Limit current	none	none	none
Under Voltage	Output is turned off	Internally drives Enable/Fault pin to Logic low	Flag is reset	Secondary part output is disabled, and fault flag is reset.
Over Voltage	Limit output voltage	None	None	None
Thermal Shutdown	Shutdown part. The part retries to start up automatically	Internally drives Enable/Fault pin to low level, and after part cools down, Enable/Fault pin will be pulled high	Flag is Set at thermal shut down, and is set to high after auto start up.	Secondary part output is disabled when thermal shut down, and is enabled after MP5003 auto start up.



THERMAL PROTECTION

The MP5003 only considers a thermal overload to be a fault. Under a fault condition the MP5003 will have two actions:

- 1) Turn off the output power device.
- 2) Drive the enable/fault pin to the low level.

The power device will remain off until the die temperature drops below the hysteresis level.

When the die cools down below the thermal hysteresis level, the MP5003 will restart in the start up mode and the fault line will be pulled high through a 25uA pull up current. If the cause of the fault has been removed, the output will ramp up in a controlled fashion with the ramp rate controlled by the dv/dt function. If the cause of the fault is still present, the excess power dissipation will heat up the part. When the die temperature reaches the thermal shutdown temperature, the output will be turned off and the enable/fault pin will be driven to the low level. This cycle will repeat until the cause of the fault is removed.

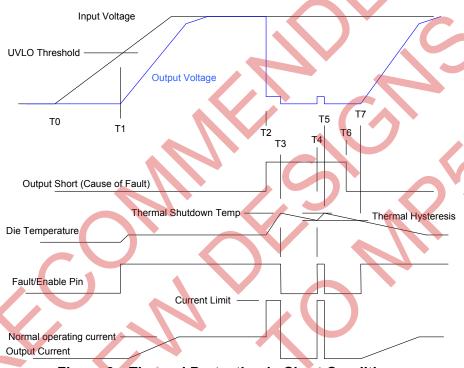


Figure 3—Thermal Protection in Short Condition

The drawing above shows the initial start up sequence and the occurrence of a short at the output.

At time T0 the input voltage begins to rise. At T1 the input voltage rises above the UVLO threshold and the part starts up. The output current ramps up and settles in at the normal operating current level until time T2. There is a very small temperature heating of the die in normal operation.

At time T2 the output is shorted. This brings the output very close to ground. The output current increases to the current limit level and is held there by the MP5003. Because of the large current and the large voltage across the power device, the die will begin to heat up.

At time T3 the die temperature is at the thermal shutdown level and the part will turn the power device off. The enable/fault pin is driven to the low level. Once the power device is off, the die temperature will begin to drop.

© 2012 MPS. All Rights Reserved.

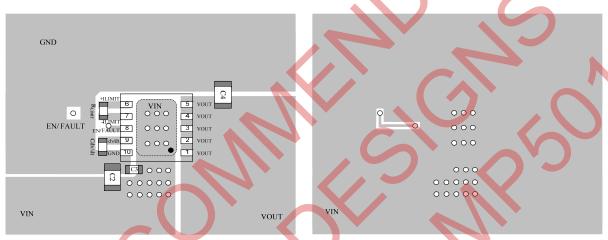
At time T4 the part has cooled down below the thermal hysteresis level. The enable pin goes high and the part turns on again. But the short is still present, causing the die temperature to increase. At time T5 the power device turns off and the Enable/Fault pin is driven to the low level, again. The temperature begins to fall.

The cycle between times T3, T4 and T5 could repeat indefinitely, but at time T6 the short is removed. At time T7 the die temperature is below the thermal hysteresis level and the part turns on once again. This time there is no short, so the output starts in normal operation and the die temperature cools down to the normal operating range.

PCB LAYOUT

PCB layout is very important to achieve stable operation. Please follow these guidelines and take below figure for reference.

Place Rlimit close to Ilimit pin, Cdv/dt close to dv/dt pin and input cap close to VIN (Exposed Pad). Keep the N/C pin float. Put vias in thermal pad and ensure enough copper area near VIN and VOUT to achieve better thermal performance.



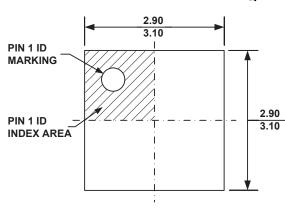
Top Layer

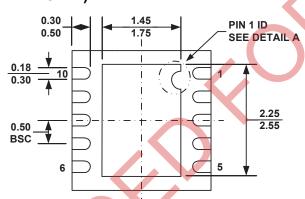
Bottom Layer

Figure 4—PCB Layout

PACKAGE INFORMATION

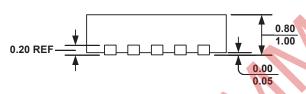
QFN10 (3mm x 3mm)



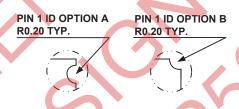


TOP VIEW

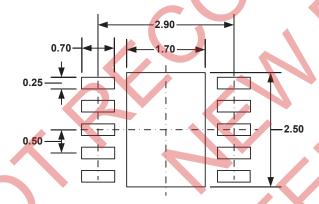
BOTTOM VIEW



SIDE VIEW



DETAIL A



RECOMMENDED LAND PATTERN

NOTE:

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETER MAX.
- 4) DRAWING CONFORMS TO JEDEC MO-229, VARIATION VEED-5.
- 5) DRAWING IS NOT TO SCALE.

NOTICE: The information in this document is subject to change without notice. Users should warrant and guarantee that third party Intellectual Property rights are not infringed upon when integrating MPS products into any application. MPS will not assume any legal responsibility for any said applications.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Power Switch ICs - Power Distribution category:

Click to view products by Monolithic Power Systems manufacturer:

Other Similar products are found below:

TLE6232GP VND5E004ATR-E FPF1018 DS1222 SZNCP3712ASNT3G NCP45520IMNTWG-H VND5004ATR-E AP22811BW5-7
SLG5NT1437VTR SZNCP3712ASNT1G DML1008LDS-7 TS13011-QFNR VND7012AYTR NCV459MNWTBG NCP4545IMNTWG-L
NCV8412ASTT1G NCV8412ASTT3G FPF2260ATMX SLG5NT1765V SLG5NT1757V NCP45780IMN24RTWG AP2151AMP-13
NCP45540IMNTWG-L XC8111AA01MR-G TPS2022P FPF2495BUCX NCP45650IMNTWG DK5V100R20S BTS7020-2EPA BTT61002ERA BTS71220-4ESA DK5V100R15M WS3220C9-9/TR AW32405CSR BTT6030-2ERA TLE75602-ESH BTS5200-4EKA
DK5V150R25M DK5V45R25 DK5V100R25S AW35206FOR BTS7120-2EPA BTS7040-1EPA BTT6030-1ERA DK5V60R10S
DK5V45R25S DK5V60R10 DK5V100R15S DK5V85R15 WS4632C-4/TR